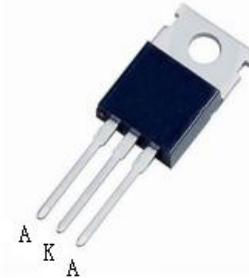
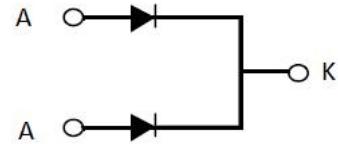


SCHOTTKY RECTIFIERS**Features:**

- High ESD capacity
- High junction temperature capability
- High frequency operation
- Low leakage current
- High surge capacity

**Applications:**

- Switching mode power supply
- High frequency inverter circuit
- Polarity protection circuit



Product Summary	
V_R	150 V
$I_F(AV)$	2*10A
T_j	150°C
$V_F(\text{max.})$	1.1 V

Absolute Maximum Ratings

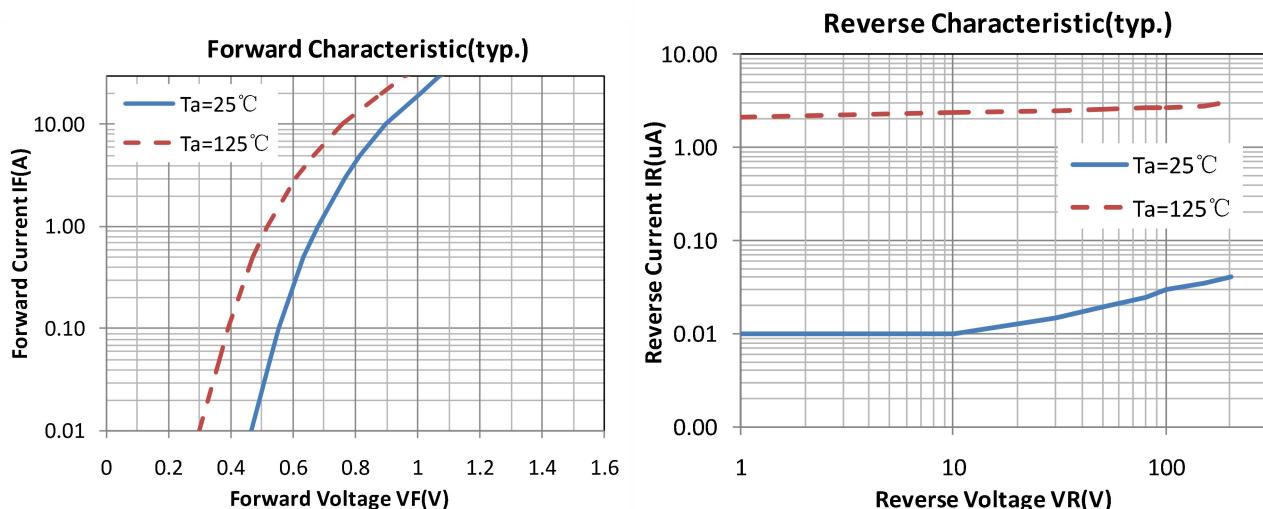
Parameter	Symbol	Values	Units
Repetitive peak reverse voltage	V_{RRM}	150	V
Continuous forward current	$I_F(AV)$	20	A
Single pulse forward current	I_{FSM}	100	
Operating junction	T_j	150	°C
Storage temperatures	T_{stg}	-55 to +150	°C
Peak Repetitive Reverse Surge Current	I_{RRM}	6	A

Electrical characteristics (Ta=25°C unless otherwise specified)						
Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V _{BR} , V _R	I _R =100μA	150			V
Forward voltage (Per Diode)	V _F	I _F =10A		0.82	1.1	
		I _F =10 A, T _j =85°C		0.75	1.0	
Reverse leakage current(Per Diode)	I _R	V _R = V _{RRM}			20	μA
		T _j =125°C , V _R =150V			10	mA

Thermal characteristics

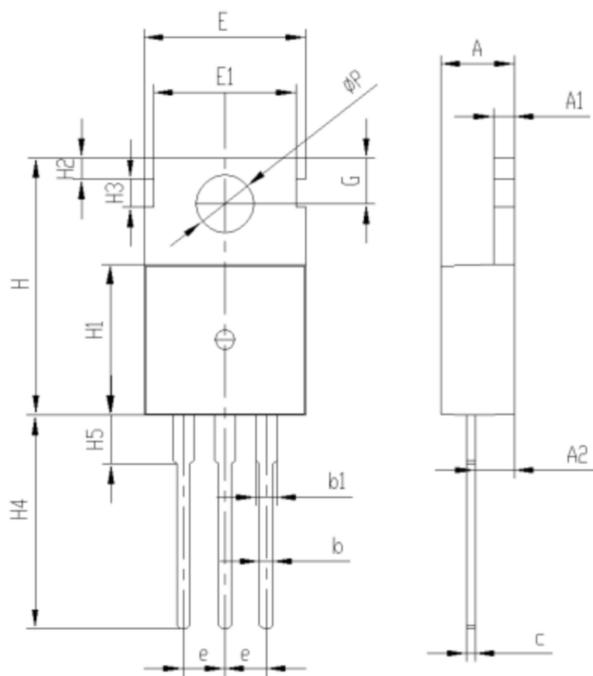
Parameter	Symbol	Typ.	Units
Junction-to-Case	R _{θJC}	3.0	°C /W

Electrical performance (typic)



Package Information

TO-220C PACKAGE



Symbol	Dimensions(millimeters)	
	Min.	Max.
A	4.30	4.70
A1	1.17	1.37
A2	2.20	2.60
b	0.60	1.00
b1	1.17	1.37
b2	1.90	2.30
c	0.30	0.70
e	2.34	2.74
E	9.70	10.1
E1	8.50	8.90
H	15.5	15.9
H1	9.00	9.40
H2	1.10	1.50
H3	1.50	1.90
H4	12.58	13.58
H5	2.80	3.20
G	2.60	3.00
ΦP	3.40	3.80